

AP3103

General Description

The AP3103 is a low startup current, current mode PWM controller with green-mode power-saving operation. The PWM switching frequency at normal operation is externally programmable and is trimmed to a tight range. The dithering of frequency will improve EMI feature. When the load decreases, the frequency will reduce and when at a very low load, the IC will enter the 'skip mode' to minimize switching loss. About 20kHz frequency switching is able to avoid the audible noise as well as reduce the standby loss.

The AP3103 features a lot of functions such as the Leading-Edge Blanking (LEB) of the current sensing, internal slope compensation and several protection functions including cycle-by-cycle current limit (OCP), VCC Over Voltage Protection (VOVP), OTP, OLP protection.

This IC is available in SOT-23-6 and DIP-8 packages.

Features

- Bi-CMOS Process with Excellent Performance
- Very Low Start-up Current:(< 15μA)
- Current Mode Control
- Non-audible-noise Green-mode Control
- LEB (Leading-edge Blanking) on SENSE Pin
- Internal Slope Compensation
- Frequency Fold Back for High Average Efficiency
- Soft Switching for Reducing EMI
- Useful Pin Fault Protection: SENSE Pin Floating RI Pin Short to Ground RI Pin Floating FB/Opt-coupler Open/short
- Comprehensive System Protection Feature: VCC Over Voltage Protection (VOVP)
 Over Temperature Protection (OTP)
 Over Load Protection (OLP)
- Mini Size with Packages

Applications

- Switching AC-DC Adapter/Charger
- ATX/BTX Auxiliary Power
- Set-top Box(STB) Power Supply
- Open Frame Switching Power Supply

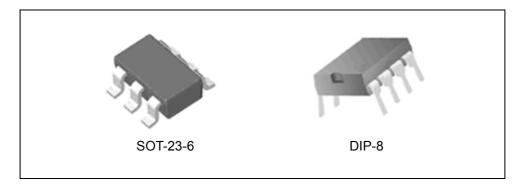


Figure 1. Package Types of AP3103



AP3103

Pin Configuration

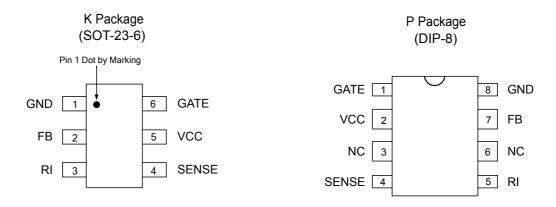


Figure 2. Pin Configuration of AP3103 (Top View)

Pin Description

Pin Number		Pin Name	Function		
SOT-23-6	DIP-8	1 in Name	runction		
1	8	GND	Signal ground. Current return for driver and control circuits		
2	7	FB	Feedback. Directly connected to the opto-coupler		
3	5	RI	et the bias current to determine the normal switching frequency		
4	4	SENSE	urrent Sense		
5	2	VCC	Supply voltage of driver and control circuits		
6	1	GATE	Gate driver output		
	3, 6	NC	No connection. These pins are not internally connected		



Functional Block Diagram

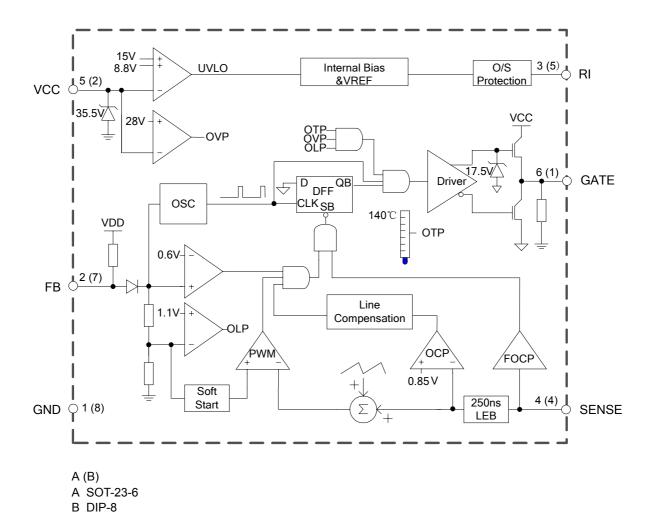
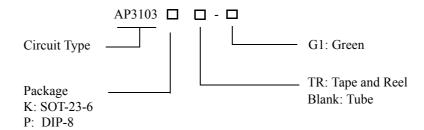


Figure 3. Functional Block Diagram of AP3103



AP3103

Ordering Information



Package	Temperature Range	Part Number	Marking ID	Packing Type
SOT-23-6	-40 to 85°C	AP3103KTR-G1	GHL	Tape & Real
DIP-8		AP3103P-G1	AP3103P-G1	Tube

BCD Semiconductor's products, as designated with "G1" suffix in the part number, are RoHS compliant and Green.



AP3103

Absolute Maximum Ratings (Note 1)

Parameter	Symbol	Value		Unit
Power Supply Voltage	V _{CC}	30		V
Gate Output Current	I_{O}	300		mA
Input Voltage to FB, SENSE pin	V _{FB} , V _{SENSE}	-0.3 to 7		V
Thermal Resistance Junction to Ambient	$ heta_{ ext{JA}}$	SOT-23-6	250	°C/W
Thermal Resistance Junction to Ambient	$O_{ m JA}$	DIP-8	100	= °C/W
Power Dissipation and Thermal Charac-	P_{D}	SOT-23-6	500	mW
teristic, SENSE at T _A <25°C		DIP-8	1250	III VV
Operating Junction Temperature	T_{J}	-40 to150		°C
Storage Temperature Range	T_{STG}	150		°C
ESD (Human Body Model)		3000		V
ESD (Machine Model)		300		V

Note 1: Stresses greater than those listed under "Absolute Maximum Ratings" may cause permanent damage to the device. These are stress ratings only, and functional operation of the device at these or any other conditions beyond those indicated under "Recommended Operating Conditions" is not implied. Exposure to "Absolute Maximum Ratings" for extended periods may affect device reliability.

Recommended Operating Conditions

Parameter	Symbol	Min	Max	Unit
Supply Voltage	V _{CC}	10	25	V
Ambient Operating Temperature Range	T_{A}	-40	85	°C



AP3103

Electrical Characteristics

 V_{CC} =16V, T_A =25°C, unless otherwise specified.

Parameter Symbol		Conditions	Min	Тур	Max	Unit	
Supply Voltage (VCC Pin)	•		•	•	•	•	
Start-up Current	I _{START-UP}	V _{CC} =14.8V		5	15	μΑ	
Operating Supply Current	I_{CC}	V_{FB} =0V, C_L =1nF, R_{RI} =100k Ω	1	2	3	mA	
operating Suppry Current	100	V_{FB} =3V, C_L =1nF, R_{RI} =100k Ω	0.65	1.65	2.65	IIIA	
UVLO (on)			13.9	15	16	V	
UVLO (off)			7.8	8.8	9.8	V	
VCC OVP			27	28	29	V	
VCC Clamp		I _{CC} =5mA	32	35.5	37	V	
PWM Section/Oscillator Sec	ction						
Maximum Duty Cycle			70	75	80	%	
Minimum Duty Cycle				0		70	
Oscillation Frequency		$R_{RI}=100k\Omega$	60	65	70	kHz	
Green Mode Frequency		$R_{RI}=100k\Omega$	22			kHz	
Frequency Temperature Stability		-40°C to 85°C			5	%	
Frequency Voltage Stability		V _{CC} =12 to 30V			3	%	
Frequency Dithering				±6		%	
Current Sense Section (SEN	SE Pin)						
Maximum SENSE Voltage	V _{CS}	V_{FB} =3.3V, R_{RI} =100k Ω , D=50%	0.800	0.850	0.900	V	
Waximum SEIVSE Voltage	· CS	V_{FB} =3.3V, R_{RI} =100k Ω , D=2.6%		0.65] '	
LEB Time of SENSE		$R_{RI}=100k\Omega$	150	250	350	ns	
Delay to Output			50	150	250	ns	
Soft-start Time		$R_{RI}=100k\Omega$		0.5		ms	
Feedback Input Section (FB	Pin)						
The Ratio of Input Voltage to Current Sense Voltage			2.5	3	3.5	V/V	
Input Impedance			3	4.5	6	kΩ	
Source Current		V _{FB} =0V	-0.5	-1	-1.5	mA	
Input Voltage for Zero Duty			1.2	1.5	1.8	V	
Output Section (GATE Pin)	l .	1		l	l	l	
Output Low Level		I _O =20mA, V _{CC} =12V			1	V	
Output High Level		I _O =20mA, V _{CC} =12V	8			V	
Output Clamping			16	17.5	19	V	
Rising Time		C _L =1nF, V _{CC} =13V	120	220	320	ns	
Falling Time		C _L =1nF, V _{CC} =13V	30	50	90	ns	



AP3103

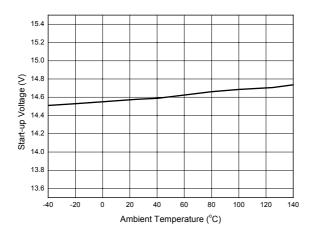
Electrical Characteristics

 V_{CC} =16V, T_A =25°C, unless otherwise specified.

Parameter	Symbol	Conditions	Min	Тур	Max	Unit
Over Temperature Protect	ion Section		•			
Shutdown Temperature				140		°C
Temperature Hysteresis				20		°C
Delay Time Section			•			
Delay 1 of Protection		OLP, R_{RI} =100 $k\Omega$		35		ms
Delay 2 of Protection		VCC OVP, R _{RI} =100kΩ		25		μs



Typical Performance Characteristics



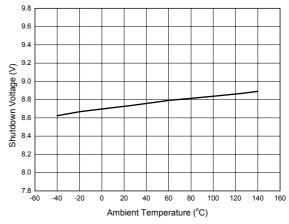
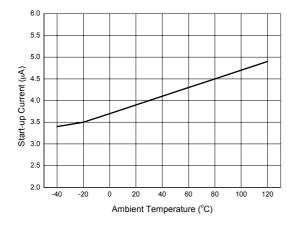


Figure 4. Start-up Voltage vs. Ambient Temperature

Figure 5. Shutdown Voltage vs. Ambient Temperature



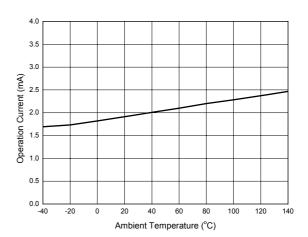
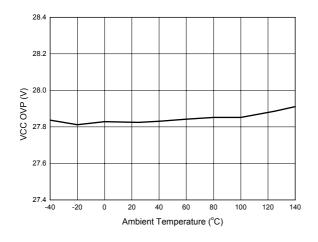


Figure 6. Start-up Current vs. Ambient Temperature

Figure 7. Operation Current vs. Ambient Temperature



Typical Performance Characteristics (Continued)



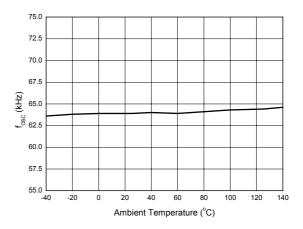


Figure 8. VCC OVP vs. Ambient Temperature

Figure 9. f_{OSC} vs. Ambient Temperature



AP3103

Operation Description

The AP3103 is specifically designed for off-line AC-DC power supply used in LCD monitor, notebook adapter and battery charger applications. It offers a cost effective solution with a versatile protection function.

Start-up Current and UVLO

The start-up current of AP3103 is optimized to realize ultra low current ($5\mu A$ typical) so that VCC capacitor can be charged more quickly. The direct benefit of low start-up current is the availability of using large start-up resistor, which minimizes the resistor power loss for high voltage AC input.

An UVLO comparator is included in AP3103 to detect the voltage on the VCC pin. It ensures that AP3103 can draw adequate energy from hold-up capacitor during power on. The turn-on threshold is 15V and the turn-off threshold is 8.8V.

Oscillator

The oscillation frequency is programmed by the value of resistor R1, connected from pin RI to ground. The resistor will make a constant current source to determine the oscillation frequency by charging and discharging an internal capacitor. Normally, RI pin should not be placed where exists too much noise, as the disturbance may make the IC work abnormally.

The oscillation frequency can be expressed as:

$$f \approx \frac{6500}{R1(k\Omega)}(kHz)$$

The recommended oscillation frequency is 50 to 100 kHz from the EMI consideration.

Current Sense Comparator and PWM Latch

The AP3103 operates as a current mode controller; the output switch conduction is initiated by every oscillator cycle and is terminated when the peak inductor current reaches the threshold level established by the FB pin. The inductor current signal is converted to a voltage signal by inserting a reference sense resistor $R_{\rm S}$. The inductor current under normal operating conditions is controlled by the voltage at FB

pin, the relation between peak inductor current (I_{PK}) and V_{FB} is:

$$I_{PK} = (V_{FB} - 0.8) / 3R_S$$

Leading-edge Blanking

A narrow spike on the leading edge of the current waveform can usually be observed when the power MOSFET is turned on. A 250ns leading-edge blank is built-in to prevent the false-triggering caused by the turn-on spike. During this period, the current limit comparator is disabled and the gate driver can not be switched off.

FB Pin and Short Circuit Protection

This pin is normally connected to the opt-coupler and always paralleled with a capacitor for loop compensation. When the voltage at this pin is great than 4.2V (such as output short to ground or the opt-coupler is broken) and lasts for about 25ms, the IC will enter the protection mode. For AP3103, the system will enter hiccup mode to wait the VCC decreasing to low UVLO level, then the IC will try to restart until the failure removed. And when this voltage is less than 1.5V, the IC will stop the drive pulse immediately. Therefore, this feature can be used for short circuit protection, which makes the system immune from catastrophic failure. Normally, output short makes the VFB value to the maximum because the opt-coupler is cut off.

System Protection and Pin Fault Protection

The AP3103 provides versatile system and pin fault protections. The OCP comparator realizes the cycle-by-cycle current limiting (OCP). In universal input line voltage, the IC realizes the constant over load protection (OLP). VCC over voltage protection can be applied as the primary OVP or opt-coupler broken protection. The AP3103 also has pin fault connection protection including floating and short connection. The floating pin protection include the RI, SENSE, FB, etc; The short pin protection includes the RI pin short protection. When these pins are floated or RI pin is shorted to ground, PWM switching will be disabled, thus protecting the power system.



Typical Application

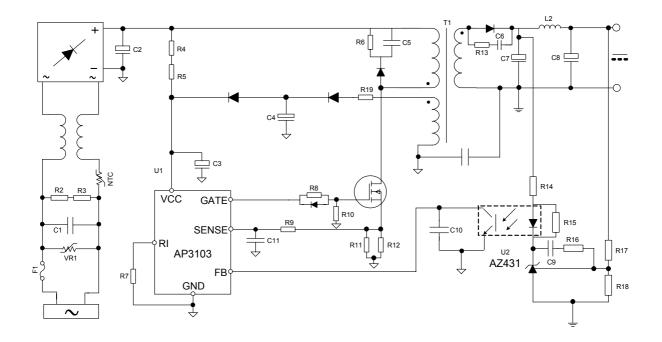
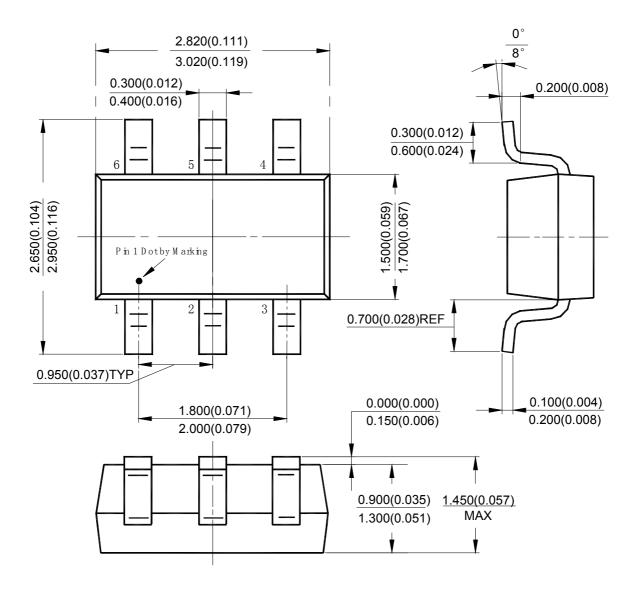


Figure 10. Typical Application of AP3103

AP3103

Mechanical Dimensions

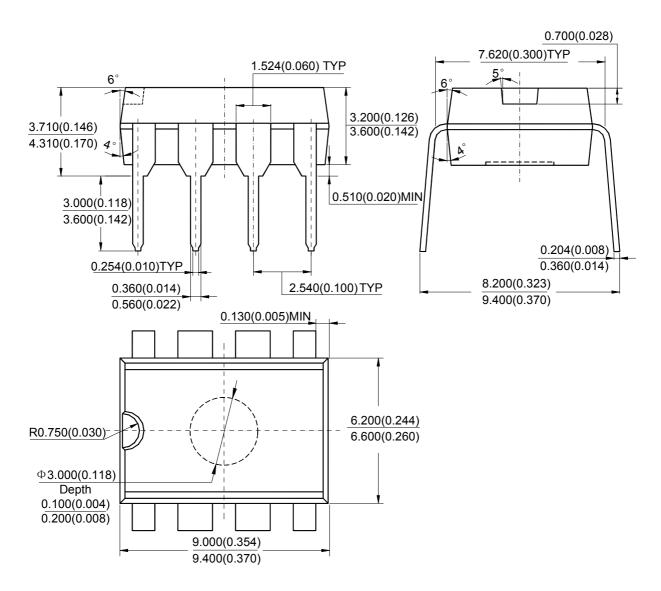
SOT-23-6 Unit: mm(inch)





Mechanical Dimensions (Continued)

DIP-8 Unit: mm(inch)



Note: Eject hole, oriented hole and mold mark is optional.





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MAIN SITE

- Headquarters

BCD Semiconductor Manufacturing Limited

No. 1600, Zi Xing Road, Shanghai ZiZhu Science-based Industrial Park, 200241, China Tel: +86-21-24162266, Fax: +86-21-24162277

REGIONAL SALES OFFICE

Shenzhen Office

Shanghai SIM-BCD Semiconductor Manufacturing Co., Ltd., Shenzhen Office Unit A Room 1203, Skyworth Bldg., Gaoxin Ave.1.S., Nanshan District, Shenzhen,

China Tel: +86-755-8826 7951 Fax: +86-755-8826 7865

- Wafer Fab

Shanghai SIM-BCD Semiconductor Manufacturing Co., Ltd. 800 Yi Shan Road, Shanghai 200233, China Tel: +86-21-6485 1491, Fax: +86-21-5450 0008

Taiwan Office

BCD Semiconductor (Taiwan) Company Limited 4F, 298-1, Rui Guang Road, Nei-Hu District, Taipei,

Taiwan Tel: +886-2-2656 2808 Fax: +886-2-2656 2806

USA Office BCD Semiconductor Corp. 30920 Huntwood Ave. Hayward, CA 94544, USA Tel: +1-510-324-2988 Fax: +1-510-324-2788